

ACJT610-10A

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|--|-------------|-----|---|
| Average gate power dissipation ($T_j=125$) | $P_{G(AV)}$ | 0.5 | W |
| Peak gate power | P_{GM} | 10 | W |
| Peak pulse voltage ($T_j=25$; non-repetitive, off-state; FIG.7) | V_{pp} | 3 | |

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